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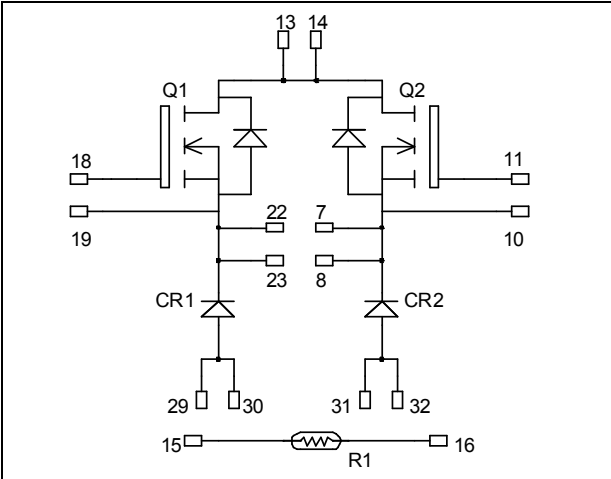
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Dual Buck chopper MOSFET Power Module

$V_{DSS} = 500V$
 $R_{DSon} = 65m\Omega \text{ typ @ } T_j = 25^\circ C$
 $I_D = 51A \text{ @ } T_c = 25^\circ C$

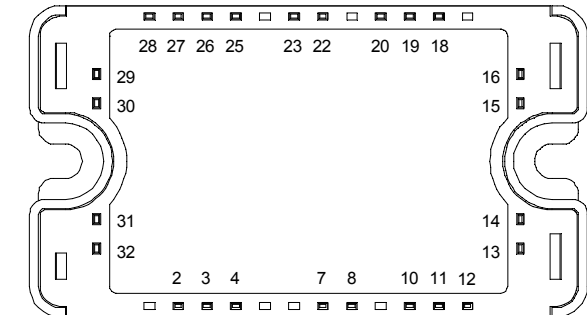


Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration



Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a single buck of twice the current capability
- RoHS Compliant

All multiple inputs and outputs must be shorted together
 Example: 13/14 ; 29/30 ; 22/23 ...

Absolute maximum ratings

| Symbol | Parameter | Max ratings | Unit |
|------------|---|--------------------|-----------|
| V_{DSS} | Drain - Source Breakdown Voltage | 500 | V |
| I_D | Continuous Drain Current | $T_c = 25^\circ C$ | 51 |
| | | $T_c = 80^\circ C$ | 38 |
| I_{DM} | Pulsed Drain current | 204 | A |
| V_{GS} | Gate - Source Voltage | ± 30 | V |
| R_{DSon} | Drain - Source ON Resistance | 78 | $m\Omega$ |
| P_D | Maximum Power Dissipation | $T_c = 25^\circ C$ | 390 |
| I_{AR} | Avalanche current (repetitive and non repetitive) | 51 | A |
| E_{AR} | Repetitive Avalanche Energy | 50 | mJ |
| E_{AS} | Single Pulse Avalanche Energy | 3000 | |

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|--------------|---------------------------------|---------------------------------------|-----|-----|-----------|------------------|
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{GS} = 0V, V_{DS} = 500V$ | | | 100 | μA |
| | | $T_j = 25^\circ\text{C}$ | | | | |
| $R_{DS(on)}$ | Drain – Source on Resistance | $V_{GS} = 0V, V_{DS} = 400V$ | | | 500 | $\text{m}\Omega$ |
| | | $T_j = 125^\circ\text{C}$ | | | | |
| $R_{DS(on)}$ | Drain – Source on Resistance | $V_{GS} = 10V, I_D = 25.5A$ | | 65 | 78 | $\text{m}\Omega$ |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{GS} = V_{DS}, I_D = 2.5\text{mA}$ | 3 | | 5 | V |
| I_{GSS} | Gate – Source Leakage Current | $V_{GS} = \pm 30V, V_{DS} = 0V$ | | | ± 100 | nA |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|--------------|------------------------------|--|-----|------|-----|---------------|
| C_{iss} | Input Capacitance | $V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1\text{MHz}$ | | 7000 | | pF |
| C_{oss} | Output Capacitance | | | 1400 | | |
| C_{rss} | Reverse Transfer Capacitance | | | 90 | | |
| Q_g | Total gate Charge | $V_{GS} = 10V$ $V_{Bus} = 250V$ $I_D = 51A$ | | 140 | | nC |
| Q_{gs} | Gate – Source Charge | | | 40 | | |
| Q_{gd} | Gate – Drain Charge | | | 70 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 333V$ $I_D = 51A$ $R_G = 3\Omega$ | | 21 | | ns |
| T_r | Rise Time | | | 38 | | |
| $T_{d(off)}$ | Turn-off Delay Time | | | 75 | | |
| T_f | Fall Time | | | 93 | | |
| E_{on} | Turn-on Switching Energy | Inductive switching @ 25°C $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 51A, R_G = 3\Omega$ | | 1035 | | μJ |
| E_{off} | Turn-off Switching Energy | | | 845 | | |
| E_{on} | Turn-on Switching Energy | Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 51A, R_G = 3\Omega$ | | 1556 | | μJ |
| E_{off} | Turn-off Switching Energy | | | 1013 | | |

Diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|-----------|---|--|---------------------------|-----|------|---------------|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | 600 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | $V_R = 600V$ | $T_j = 25^\circ\text{C}$ | | 350 | μA |
| | | | $T_j = 125^\circ\text{C}$ | | 600 | |
| I_F | DC Forward Current | | | 80 | | A |
| V_F | Diode Forward Voltage | $I_F = 80A$ | $T_j = 25^\circ\text{C}$ | | 1.45 | V |
| | | | $T_j = 125^\circ\text{C}$ | | 1.35 | |
| t_{rr} | Reverse Recovery Time | $I_F = 80A$ $V_R = 300V$ $di/dt = 4500A/\mu\text{s}$ | $T_j = 25^\circ\text{C}$ | | 95 | ns |
| | | | $T_j = 125^\circ\text{C}$ | | 115 | |
| Q_{rr} | Reverse Recovery Charge | $I_F = 80A$ $V_R = 300V$ $di/dt = 4500A/\mu\text{s}$ | $T_j = 25^\circ\text{C}$ | | 5.2 | μC |
| | | | $T_j = 125^\circ\text{C}$ | | 8 | |

Thermal and package characteristics

| Symbol | Characteristic | Min | Typ | Max | Unit | |
|-------------------|--|-------------|-----|------|------|-----|
| R _{thJC} | Junction to Case Thermal Resistance | Transistor | | 0.32 | °C/W | |
| | | Diode | | 0.8 | | |
| V _{ISOL} | RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz | 4000 | | | V | |
| T _J | Operating junction temperature range | -40 | | 150 | °C | |
| T _{STG} | Storage Temperature Range | -40 | | 125 | | |
| T _C | Operating Case Temperature | -40 | | 100 | | |
| Torque | Mounting torque | To heatsink | M4 | 2 | 3 | N.m |
| Wt | Package Weight | | | | 110 | g |

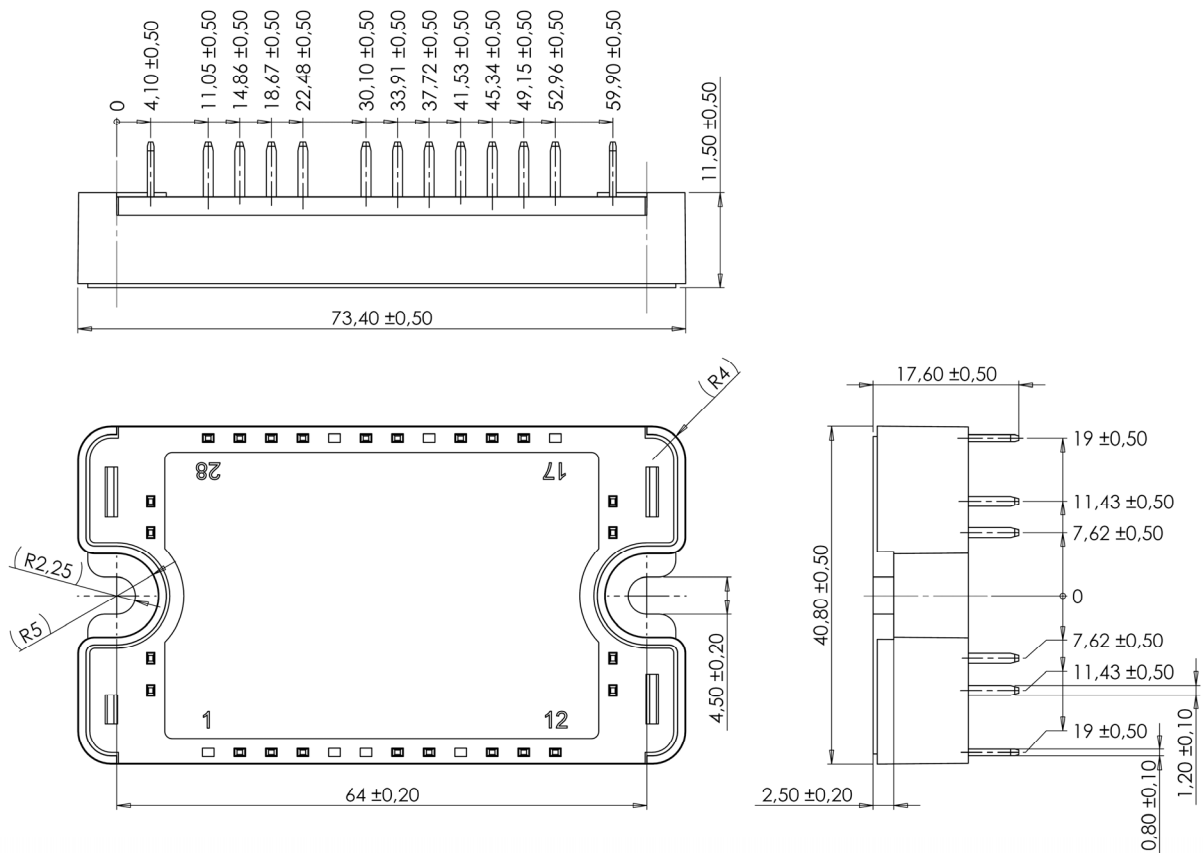
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

| Symbol | Characteristic | Min | Typ | Max | Unit |
|--------------------|----------------------------|-----|------|-----|------|
| R ₂₅ | Resistance @ 25°C | | 50 | | kΩ |
| B _{25/85} | T ₂₅ = 298.15 K | | 3952 | | K |

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$

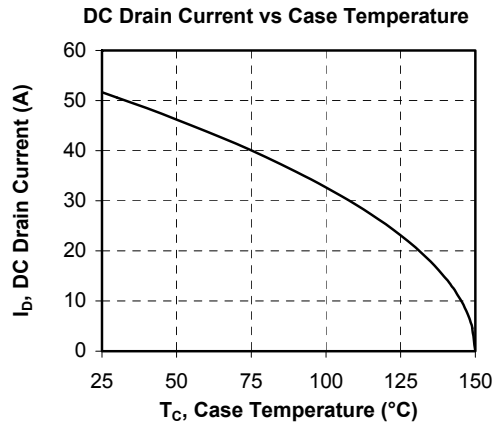
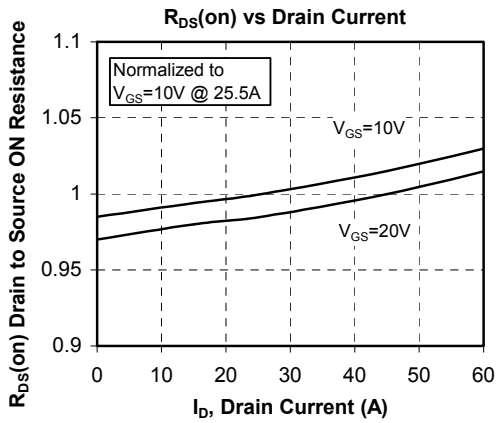
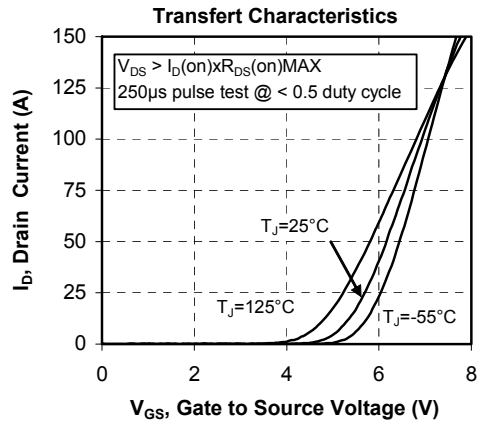
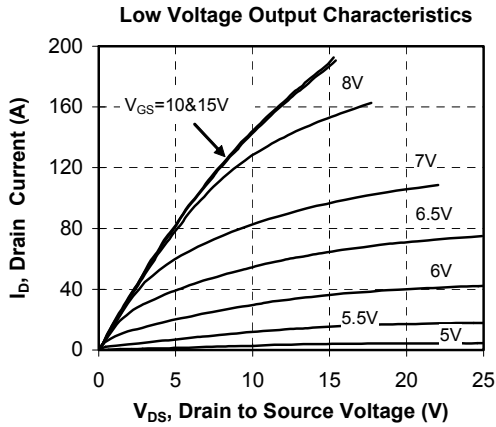
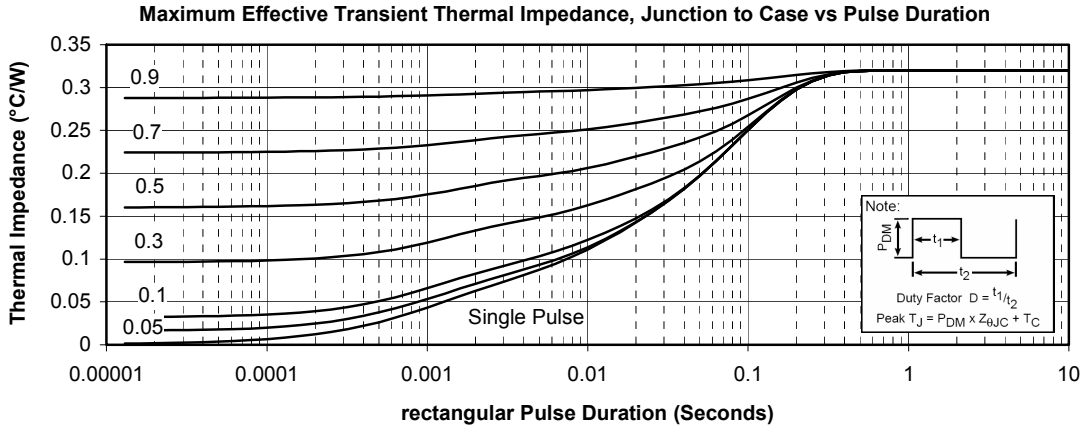
T: Thermistor temperature
 R_T: Thermistor value at T

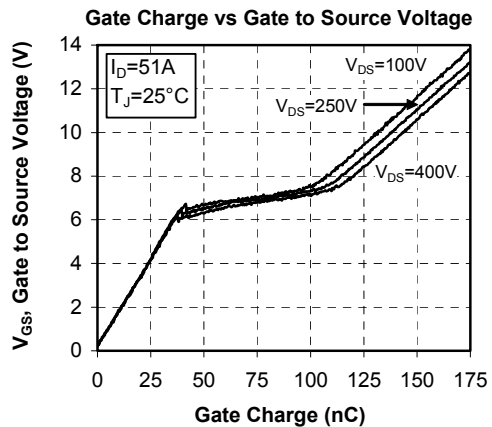
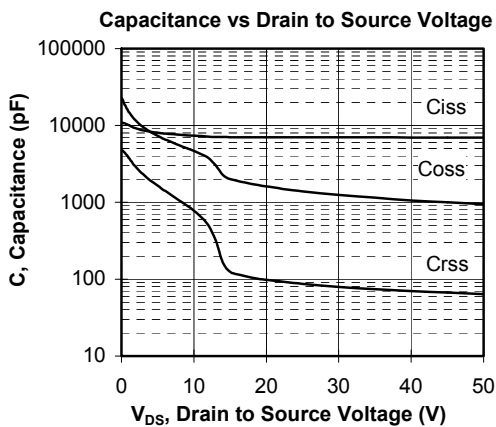
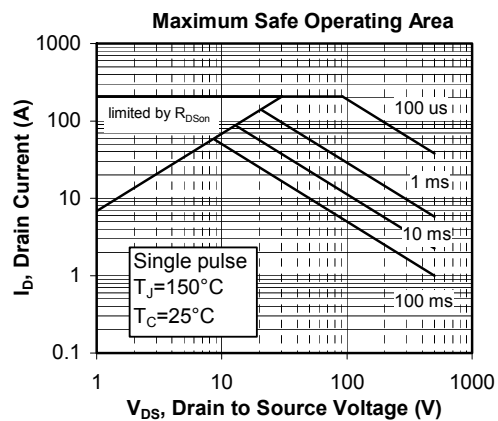
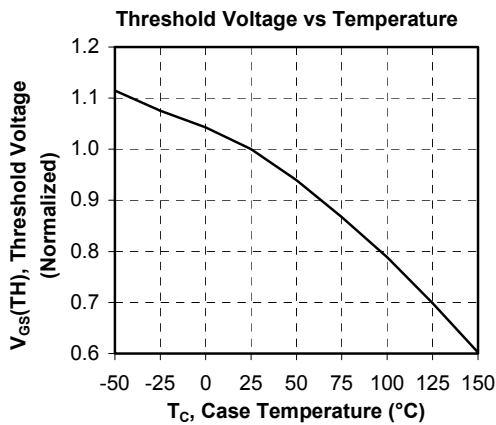
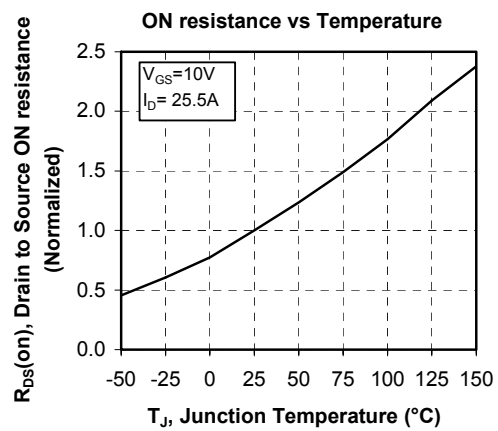
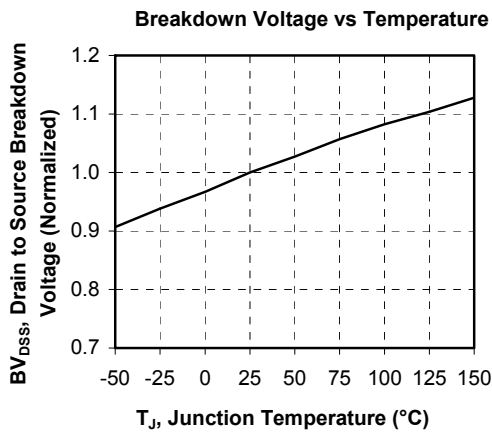
SP3 Package outline (dimensions in mm)

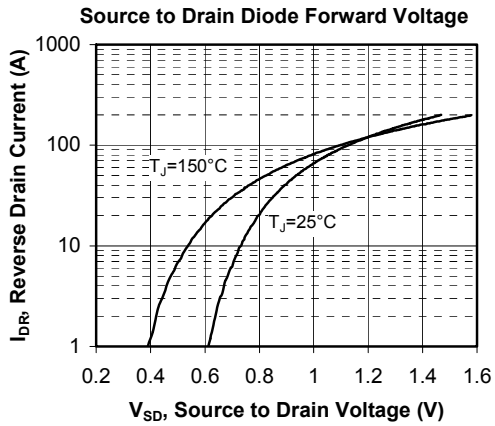
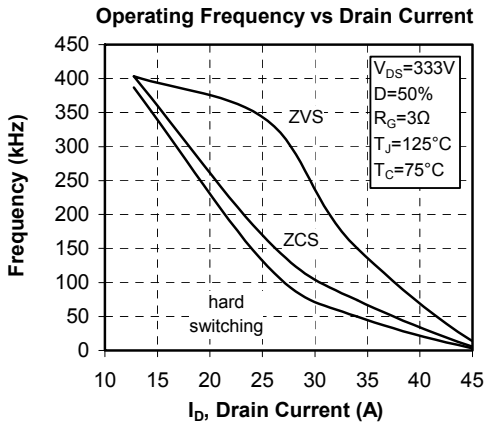
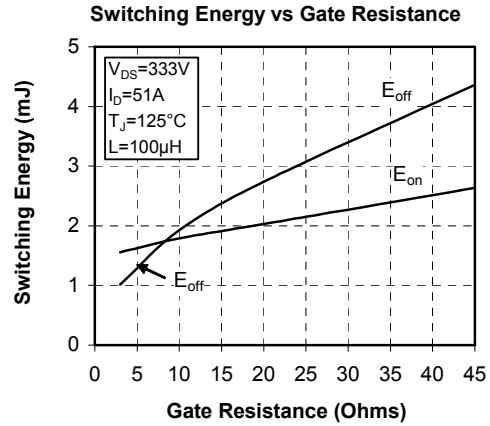
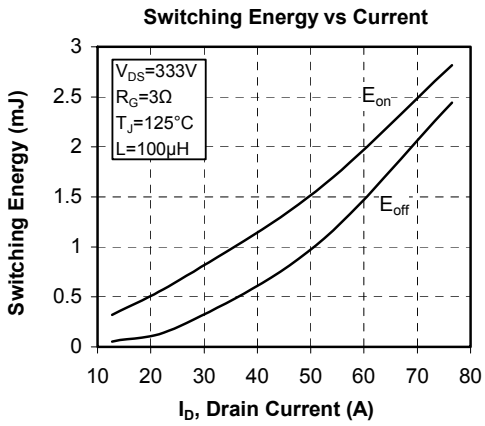
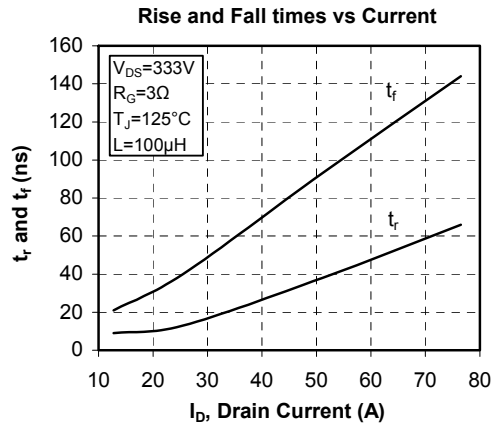
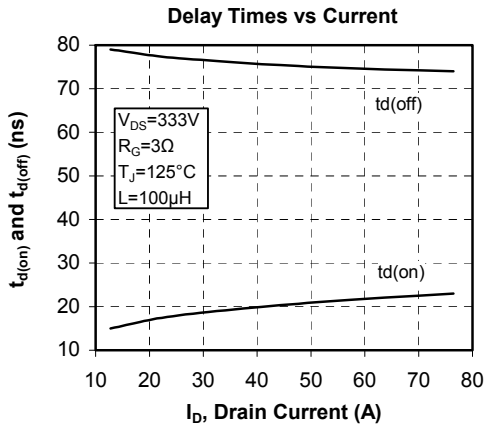


See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

Typical Performance Curve







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